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APPLICATION NO).	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/791,337	•	03/01/2004	David Pritchard	03-2051/LSI1P240 2401		
24319	7590	05/22/2006		EXAMINER		
		ORATION	TRINH, MICHAEL MANH			
1621 BAR MS: D-106		E		ART UNIT PAPER NUMBER 2822		
MILPITAS	S, CA 950	035				
				DATE MAILED: 05/22/2000	6	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/791,337	PRITCHARD ET AL.	
Office Action Summary	Examiner	Art Unit	
	Michael Trinh	2822	
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address	
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. hely filed the mailing date of this communicatio	
Status			
1) Responsive to communication(s) filed on 28 Fe 2a) This action is FINAL. 2b) This 3) Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro		s
Disposition of Claims			
4) Claim(s) 2-15 and 18-25 is/are pending in the a 4a) Of the above claim(s) is/are withdraw 5) Claim(s) is/are allowed. 6) Claim(s) is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) 2-15 and 18-25 are subject to restriction Application Papers 9) The specification is objected to by the Examiner 10) The drawing(s) filed on is/are: a) access applicant may not request that any objection to the of Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Examiner	on and/or election requirement. cpted or b) objected to by the Edrawing(s) be held in abeyance. See on is required if the drawing(s) is objected to be the drawing(s).	37 CFR 1.85(a). ected to. See 37 CFR 1.121(c	1).
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priori application from the International Bureau * See the attached detailed Office action for a list of	have been received. have been received in Application ty documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage	
Attachment(s) Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary (Paper No(s)/Mail Dat 5) Notice of Informal Pa 6) Other:	e	

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DETAILED ACTION

** This office action is in response to Applicant's Amendment filed February 28, 2006. Claims 2-15 and 18-25 are pending. In view of Applicant's amendment, newly added claims 18-25, and separate remarks for each claimed inventions, a restriction requirement is as follows:

Election/Restriction

- 1. This application contains claims directed to the following patentably distinct species, combination, subcombination of the claimed invention:
- ** Group I, claims 2,4-11, Figures 1A-1O, a first method includes at least the steps of etching where the gate electrode trench etch stops on the underlying substrate.
- ** Group II, claims 3,12-15, Figs 2A-2G, a second method includes at least the step of etching a gate electrode trench extends into the substrate a depth sufficient to include an entire device inversion channel.
- ** Group III, newly added claims 18-25, a method includes at least the steps of providing a semiconductor substrate having isolation structures, forming source and drain diffusions; after annealing the source and drain diffusion, covering the semiconductor substrate with a first layer of dielectric material.
- *** Accordingly, in response to this office action, Applicant is required under 35 U.S.C. 121 to elect a single disclosed species of either Group I, claims 2,4-11 or Group II, claims 3,12-15, for prosecution on the merits to which the claims shall be restricted if no generic claim is finally held to be allowable, since Group III, newly added Claims 18-25, is constructively withdrawn from consideration as being directed to a non-elected invention, and since applicant has received an action on the merits for the originally presented invention of subject matter of Groups I-II, claims 2-15, and constructively elected by original presentation and examination for prosecution on the merits. See 37 CFR 1.142(b) and MPEP § 821.03.

Currently, there is no generic claim. Base claim 2 of Group I evidently requires at least the steps of etching where the gate electrode trench etch stops on the underlying substrate; whereas, base claim 3 of Group II evidently differently requires at least the step of etching a gate electrode trench extends into the substrate a depth sufficient to include an entire device inversion channel; and whereas, Group III, new base claim 18, does not require etching where the gate

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electrode trench etch stops on the underlying substrate or etching a gate electrode trench extends into the substrate a depth sufficient to include an entire device inversion channel, but differently requires a semiconductor substrate having isolation structures, forming source and drain diffusions; after annealing the source and drain diffusion, covering the semiconductor substrate with a first layer of dielectric material. No claim is generic.

Applicant is advised that a reply to this requirement must include an identification of the species that is elected consonant with this requirement, and a listing of all claims readable thereon, including any claims subsequently added. An argument that a claim is allowable or that all claims are generic is considered nonresponsive unless accompanied by an election.

Upon the allowance of a generic claim, applicant will be entitled to consideration of claims to additional species which are written in dependent form or otherwise include all the limitations of an allowed generic claim as provided by 37 CFR 1.141. If claims are added after the election, applicant must indicate which are readable upon the elected species. MPEP § 809.02(a). Should applicant traverse on the ground that the species are not patentably distinct, applicant should submit evidence or identify such evidence now of record showing the species to be obvious variants or clearly admit on the record that this is the case. In either instance, if the examiner finds one of the inventions unpatentable over the prior art, the evidence or admission may be used in a rejection under 35 U.S.C. 103(a) of the other invention.

Applicant is reminded that upon the cancellation of claims to a non-elected invention, the inventorship must be amended in compliance with 37 CFR 1.48(b) if one or more of the currently named inventors is no longer an inventor of at least one claim remaining in the application. Any amendment of inventorship must be accompanied by a petition under 37 CFR 1.48(b) and by the fee required under 37 CFR 1.17(i).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michael M. Trinh whose telephone number is (571) 272-1847. The examiner can normally be reached on M-F: 9:00 Am to 5:30 Pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra Smith can be reached on (571) 272-2429. The central fax phone number is (703) 872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). Oacs-18

Michael Trimin Primary Examiner